

T489D226K025ATA650

T489 Auto, Tantalum, MnO₂ Tantalum, Commercial Grade, 22 uF, 10%, 25 VDC, SMD, MnO₂, Molded, Low Leakage, Auto, AEC-Q200, 650 mOhms, 3.1 mm, 2817 / 7343



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General Information

Series	T489 Auto
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, Low Leakage, Auto, AEC-Q200
Features	Low Leakage, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
Typical Component Weight	446.844 mg

Dimensions

L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

Specifications

Capacitance	22 uF
Tolerance	10%
Voltage DC	25 VDC (85C), 16.75 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
ESR	650 mOhms (100kHz 25C)
Ripple Current	480 mA (rms, 100kHz 25C)
Leakage Current	4.1 uA (5min 25°C)

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

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